Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-175-5165

Inclosure Mate	
Glass	
Overall Length	1:
0.357 inches	
Terminal Leng	th:
1.000 inches	
Overall Diame	ter:
0.235 inches	
Function For W	Which Designed:
Transient supp	ressor
Joint Electron	ic Device Engineering Council/jedec/case Outline Designation:
Do-13	
Mounting Met	nod:
Terminal	
Features Prov	ided:
Hermetically se	aled case
Semiconducto	or Material:
Silicon	
Voltage Rating	In Volts Per Characteristic:
21.0 reverse b	reakdown voltage, dc
Current Rating	g Per Characteristic:
5.00 microamp	eres forward current, average peak
Power Rating	Per Characteristic:
1.0 watts small-	-signal input power, common-collector major
Maximum Ope	rating Tempurature Per Measurement Point:
175.0 degrees	celsius ambient air
Test Data Doc	ument:
81349-mil-s-19	500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specifica
format; exclude	es commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental a	and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type	And Quantity:
2 uninsulated w	vire lead
Specification I	Data:
81349-mil-s-19	500/507 government specification
Shelf Life:	
N/a	
Unit Of Measu	re:
Demilitarizatio	n:
No	
Fiig:	
A110a0	